

Fig. 5. Unit-cell packing for (4).
(Sobolev, Chetkina, Gol'der, Federov \& Zavodnik, 1973; Grigor'eva, Chetkina, Neigauz \& Gol'der, 1975; Grigor'eva \& Chetkina, 1977).

The imide ring $C$ consists of three consecutive aromatic carbons, two carbonyl carbons, and a tertiary N . In each structure the observed $\mathrm{C}\left(1 b^{\prime}\right)-\mathrm{N}(1)-\mathrm{C}\left(8 b^{\prime}\right)$ angle at $\mathrm{N}(1)$ deviates from the tetrahedral angle (the
angles average $125.6^{\circ}$ in the four compounds) indicating considerable electron withdrawal by the adjacent imide carbonyls. The cations in each structure are essentially planar.

The unit-cell packing arrangements for compounds (1) to (4) are illustrated in Figs. 2 to 5.

## References

Bowler, B. E., Hollis, L. S. \& Lippard, S. J. (1984). J. Am. Chem. Soc. 106, 6102-6104.
Grigor'eva, L. P. \& Chetkina, L. A. (1977). Zh. Strukt. Khim. 18, 908-916.
Grigor'eva, L. P., Chetkina, L. A., Neigauz, M. G. \& Gol'der, G. A. (1975). Kristallografiya, 20, 303-308.

International Tables for X-ray Crystallography (1974). Vol. IV. Birmingham: Kynoch Press (Present distributor Kluwer Academic Publishers, Dordrecht.)
North, A. C. T., Phillips, D. C. \& Mathews, F. S. (1968). Acta Cryst. A24, 351-359.
Sheldrick, G. M. (1976). SHELX76. Program for crystal structure determination. Univ. of Cambridge, England.
Sobolev, A. N., Chetkina, L. A., Gol'der, G. A., Federov, Yu. G. \& Zavodnik, V. E. (1973). Kristallografiya, 18, 1157-1161.

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# 1,3,3,5,5,7,9,9,11,11-Decamethyl-2,4,6,8,10,12-hexaoxa-1,3,5,7,9,11-hexasilabicyclo[5.5.2]tetradecane 

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Abstract. $\mathrm{C}_{12} \mathrm{H}_{34} \mathrm{O}_{6} \mathrm{Si}_{6}, \quad M_{r}=442.9$, orthorhombic, Pcan, $\quad a=12.083$ (1), $\quad b=12.083(1), \quad c=$ $17.702(1) \AA, \quad V=2584.3(3) \AA^{3}, \quad Z=4, \quad D_{x}=$ $1.138 \mathrm{Mg} \mathrm{m}^{-3}, \quad \lambda($ Мо Ka) $=0.71069 \AA, \quad \mu=$ $0.34 \mathrm{~mm}^{-1}, F(000)=952, T=297 \mathrm{~K}, R=0.047$ for 969 observed reflections. The molecule has a twofold symmetry axis; the conformation of the hexasiloxane ring is a twisted saddle, the dihedral angle between the winge being $98.4(3)^{\circ}$. The SiCCSi bridge has a synclinal conformation with a torsion angle of $67.3(5)^{\circ}$. The crystal structure is loose with molecules forming layers coplanar to the $a b$ and $b c$ planes.

Introduction. Earlier we determined the crystal structure of a cyclotetrasiloxane with an intracyclic $-\mathrm{CH}_{2} \mathrm{CH}_{2}-$ bridge (I) (Ovchinnikov, Shklover,

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Struchkov, Astapova \& Zhdanov, 1986). In this work the molecular and crystal structure of the cyclohexasiloxane analogue (II) is reported. Like (I), molecule (II) represents a single unit of the carbocyclosiloxane polymer (see below), a structural study of which is proposed in the future.


Experimental. Irregular-shaped single crystal $0.8 \times$ $0.6 \times 0.4 \mathrm{~mm}$ used for measurements of unit-cell parameters ( 12 reflections with $28 \leq 2 \theta \leq 32^{\circ}$ ) and © 1989 International Union of Crystallography
intensities of 1334 reflections ( $0 \leq h \leq 12,0 \leq k \leq 12$, $0 \leq l \leq 19$ ). Hilger \& Watts diffractometer (graphite monochromator, $\theta / 2 \theta$ scan, $2 \theta_{\max }=56^{\circ}$ ). Despite the coincidence of two parameters of the orthorhombic cell, the intensities in $h k l, k \bar{h} l, \bar{h} k l$, and $\bar{k} h l$ groups differed greatly, i.e. a fourfold symmetry axis was absent. Space group Pcan determined from systematic absences. In the course of data collection intensities of two standard reflections measured after every 100 reflections were reduced by ca five times because of surface melting ( $T_{m}=321 \mathrm{~K}$ ), so intensities of all reflections were corrected according to the drift of the standard reflections with a special program. No absorption or secondary-extinction corrections. Structure solved by direct methods (MULTAN program; Germain, Main \& Woolfson, 1971) and refined by block-diagonal least squares with anisotropic thermal parameters for non-H atoms using 969 unique reflections with $F>5 \sigma(F)$ and minimizing $\sum w\left(\left|F_{o}\right|-\left|F_{c}\right|\right)^{2} ; \quad w=\left[\sigma^{2}\left(F_{o}\right)+\right.$ $\left.0.01 F_{0}^{2}\right]^{-1}$. Scattering factors from International Tables for X-ray Crystallography (1974). H atoms located by a difference synthesis and refined isotropically. Final $R=0.047, w R=0.049, S=2.68$, max. $\Delta / \sigma=0.3$, final electron density fluctuations $\pm 0.4 \mathrm{e} \AA^{-3}$. All calculations carried out with an Eclipse S/200 computer using the INEXTL programs (Gerr, Yanovsky \& Struchkov, 1983).

Discussion. Atomic coordinates are given in Table 1,* relevant bond lengths and bond angles in Table 2. A perspective view of molecule (II) with the atom numbering is shown in Fig. 1.

The presence of the $-\mathrm{CH}_{2} \mathrm{CH}_{2}-$ bridge distorting the 'normal' geometry of siloxane rings determines the similarity of the molecular structures (I) and (II). As in (I), the siloxane ring in (II) has a 'saddle' conformation, the SiCCSi bridge has a synclinal con-

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Fig. 1. Perspective view of molecule (II). H atoms are omitted. For symmetry code see Table 2.

Table 1. Atomic coordinates ( $\times 10^{5}$ for $\mathrm{Si}, \times 10^{4}$ for O and C ) and equivalent isotropic temperature factors $\left(\AA^{2}\right)$

|  | $B_{\text {eq }}=\frac{1}{3} \sum_{l} \sum_{j} \boldsymbol{B}_{i j} a_{i}^{*} a_{j}^{*}\left(\mathbf{a}_{i}, \mathbf{a}_{j}\right)$. |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | $x$ | $y$ | $z$ | $B_{\text {eq }}$ |
| Si(1) | 20929 (18) | 48597 (11) | 14453 (8) | 5.19 (5) |
| Si(2) | 33503 (18) | 26649 (12) | 16813 (7) | 5.47 (5) |
| $\mathrm{Si}(3)$ | 39905 (16) | 33802 (12) | 33194 (8) | $5 \cdot 18$ (5) |
| O(1) | 2381 (4) | 3562 (3) | 1543 (2) | 6.0 (1) |
| $\mathrm{O}(2)$ | 3906 (4) | 2866 (3) | 2491 (2) | 9.5 (2) |
| O(3) | 3197 (4) | 4447 (3) | 3380 (2) | $6 \cdot 3$ (1) |
| C(1) | 979 (5) | 5249 (4) | 2107 (3) | 6.9 (2) |
| C(2) | 1667 (8) | 5114 (5) | 451 (3) | 10.5 (3) |
| C(3) | 4408 (7) | 2825 (5) | 953 (4) | 9.9 (3) |
| C(4) | 2727 (7) | 1283 (4) | 1683 (3) | 9.1 (3) |
| C(5) | 5422 (6) | 3813 (5) | 3491 (4) | 9.6 (3) |
| C(6) | 3582 (7) | 2327 (5) | 4014 (3) | 9.4 (3) |

Table 2. Relevant bond lengths $(\AA)$ and bond angles $\left({ }^{\circ}\right)$

| $\mathrm{Si}(1)-\mathrm{O}(1)$ | $1.615(3)$ | $\mathrm{Si}(1)-\mathrm{C}(2)$ | $1.860(6)$ |
| :--- | :---: | :--- | ---: |
| $\mathrm{Si}(1)-\mathrm{O}\left(3^{\prime}\right)$ | $1.605(5)$ | $\mathrm{Si}(2)-\mathrm{C}(3)$ | $1.826(8)$ |
| $\mathrm{Si}(2)-\mathrm{O}(1)$ | $1.615(4)$ | $\mathrm{Si}(2)-\mathrm{C}(4)$ | $1.832(6)$ |
| $\mathrm{Si}(2)-\mathrm{O}(2)$ | $1.602(4)$ | $\mathrm{Si}(3)-\mathrm{C}(5)$ | $1.833(8)$ |
| $\mathrm{Si}(3)-\mathrm{O}(2)$ | $1.595(4)$ | $\mathrm{Si}(3)-\mathrm{C}(6)$ | $1.836(6)$ |
| $\mathrm{Si}(3)-\mathrm{O}(3)$ | $1.610(4)$ | $\mathrm{C}(1)-\mathrm{C}\left(1^{\prime}\right)$ | $1.514(7)$ |
| $\mathrm{Si}(1)-\mathrm{C}(1)$ | $1.845(6)$ |  |  |
| $\mathrm{O}(3) \mathrm{Si}(1) \mathrm{O}(1)$ |  |  |  |
| $\mathrm{O}(1) \mathrm{Si}(2) \mathrm{O}(2)$ | $107.9(2)$ | $\mathrm{Si}(3) \mathrm{O}(3) \mathrm{Si}\left(1^{\prime}\right)$ | $157.8(3)$ |
| $\mathrm{O}(2) \mathrm{Si}(3) \mathrm{O}(3)$ | $109.8(2)$ | $\mathrm{Si}(1) \mathrm{C}(1) \mathrm{C}\left(1^{\prime}\right)$ | $118.8(4)$ |
| $\mathrm{Si}(1) \mathrm{O}(1) \mathrm{Si}(2)$ | $109.6(2)$ | $\mathrm{C}(1) \mathrm{Si}(1) \mathrm{C}(2)$ | $110.9(3)$ |
| $\mathrm{Si}(2) \mathrm{O}(2) \mathrm{Si}(3)$ | $155.5(3)$ | $\mathrm{C}(3) \mathrm{Si}(2) \mathrm{C}(4)$ | $112.7(3)$ |
|  |  |  | $\mathrm{C} .3(3)$ |
|  |  | $\mathrm{C}(5) \mathrm{Si}(3) \mathrm{C}(6)^{*}$ | $109.9(3)$ |

Symmetry code: (i) $x, 1-y, \frac{1}{2}-z$.

* The OSiC angles are $108.0-110.5^{\circ}$, e.s.d.'s $0 \cdot 2-0.3^{\circ}$.
formation, the SiCC bond angles of 118.8 (4) ${ }^{\circ}$ are much greater than the tetrahedral value, and the molecule also has crystallographic $C_{2}$ symmetry (twofold axis passing through the middle of the $\mathrm{C}-\mathrm{C}$ bond). However, as the increase of a ring dimension enhances the ring's flexibility, significant differences between (I) and (II) result. The dihedral angle between the mean planes of the 'wings' $\mathrm{Si}(1) \mathrm{O}(1) \mathrm{Si}(2) \mathrm{O}(2) \mathrm{Si}(3) \mathrm{O}(3) \mathrm{Si}\left(1^{\prime}\right)$ and $\mathrm{Si}\left(1^{\prime}\right) \mathrm{O}\left(1^{\prime}\right) \mathrm{Si}\left(2^{\prime}\right) \mathrm{O}\left(2^{\prime}\right) \mathrm{Si}\left(3^{\prime}\right) \mathrm{O}\left(3^{\prime}\right) \mathrm{Si}(1)$ in (II) is 98.4 (3) vs $115.0(6)^{\circ}$ in (I). Nonplanarity of the wings is somewhat greater; the maximum deviation of the atoms from the mean wing plane in (II) is 0.445 (4) $v s$ 0.210 (6) $\AA$ in (I). The greater flexibility of the ring allows molecule (II) to adopt a less strained conformation, which is displayed, in particular, in the increase of the non-bonded $\mathrm{Si}(1) \cdots \operatorname{Si}\left(1^{\prime}\right)$ distance up to 3.750 (2) $\AA[3.442$ (4) $\AA$ in (I)], a considerably 'untwisted' conformation of the bridge [SiCCSi torsion angle of 67.3 (5) in (II) $v s 39.1^{\circ}$ in (I)], and shortening of the $\mathrm{C}-\mathrm{C}$ bond to 1.514 (7) $\AA$, which is less than the standard $\mathrm{C}\left(s p^{3}\right)-\mathrm{C}\left(s p^{3}\right)$ bond [1.563 (5) $\AA$ in (I)]. It is interesting that even the SiCC bond angle of 118.8 (4) ${ }^{\circ}$ in (II) exceeds the corresponding angle of 117.1 (2) ${ }^{\circ}$ in (I). Apparently, an energy gain in other parameters


Fig. 2. Stereopair showing the molecular packing in (II).
compensates the increase of conformational energy caused by this enlargement of the angle.

The mean $\mathrm{Si}-\mathrm{O}$ bond length of 1.608 (3) $\AA$ in (II) is somewhat smaller than the value of $1.625 \AA$ which is usual for sterically non-overloaded tetrasiloxanes with nearly the same values of the SiOSi bond angles (Shklover \& Struchkov, 1980). It emphasizes the absence of significant strain in the siloxane ring in (II); on the contrary, in molecule (I) a small lengthening of
the $\mathrm{Si}-\mathrm{O}$ bonds and a noticeable decrease of the bond angles at the O atoms are observed in comparison with the usual angles in tetrasiloxanes. Other bond lengths and bond angles in (II) are ordinary.

The crystal structure of (II) is very loose; there is only one intermolecular contact less than $4 \AA$ : C(6)... $\mathrm{C}(2)\left(\frac{1}{2}-x, \frac{1}{2}-y, \frac{1}{2}+z\right)$ of 3.907 (7) $\AA$. The layers of molecules, which are coplanar to the crystallographic $a b$ and $b c$ planes, are clearly distinguished (Fig. 2). It is possible that the mobility of these layers is the cause for crystals of (II) becoming shapeless without a decrease of rigidity in 2-3 days at room temperature.

## References

Germain, G., Main, P. \& Woolfson, M. M. (1971). Acta Cryst. A27, 368-376.
Gerr, R. G., Yanovsky, A. I. \& Strucheov, Yu. T. (1983). Kristallografiya, 28, 1029-1030.
International Tables for X-ray Crystallography (1974). Vol. IV. Birmingham: Kynoch Press. (Present distributor Kluwer Academic Publishers, Dordrecht.)
Ovchinnikov, Yu. E., Shklover, V. E., Struchkov, Yu. T., Astapova, T. V. \& Zhdanov, A. A. (1986). Z. Anorg. Allg. Chem. 533, 159-164.
Shilover, V. E. \& Struchiov, Yu. T. (1980). Usp. Khim. 49, 518-556.

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# Structure of a Planar Organic Compound: 2,1,3-Benzoselenadiazole (Piaselenole) 

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Abstract. $\quad \mathrm{C}_{6} \mathrm{H}_{4} \mathrm{~N}_{2} \mathrm{Se}, \quad M_{r}=183 \cdot 11$, orthorhombic, Pna2 ${ }_{1}, \quad a=12.553$ (4), $\quad b=12.414$ (3),$\quad c=$ 3.941 (1) $\AA, V=614.2 \AA^{3}, Z=4, D_{x}=1.98 \mathrm{~g} \mathrm{~cm}^{-3}$, $\lambda($ Mo $K \alpha)=0.7107 \AA, \mu=6.46 \mathrm{~cm}^{-1}, \quad F(000)=352$, $T=288$ K. Final $R=0.044$ for 747 observed reflections. The molecule is planar within experimental error. The mean $\mathrm{N}-$ Se distance is 1.784 (5) $\AA$, and a pseudo $C_{2 v}$ axis is observed in the molecule.

Introduction. The structure determination of the title compound (received through the courtesy of Dr Wirz of Universität Basel, Switzerland) was undertaken as part of a series of studies of carcinogenic heterocyclic

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planar chromophoric organic compounds, seeking structure-function correlations because these compounds are important for their selective intercalation in DNA and for chemotherapeutic uses. Structural elucidation of these series of compounds may also explain physical properties, such as cleavage and melting point, and may clarify salient features of the effect of intermolecular binding forces.
The primary synthesis and chemical characterization reports concerning piaselenole and others were published by Hinsberg (1889) and Zincke \& Schwartz (1899); the 2D structure was reported by Luzzati (1951) and subsequently further NMR studies and molecular orbital calculations have been undertaken (Rettig \& Wirz, 1976). This paper presents a complete © 1989 International Union of Crystallography


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[^1]:    * Lists of structure factors, anisotropic thermal parameters and H -atom parameters have been deposited with the British Library Document Supply Centre as Supplementary Publication No. SUP 51087 (11 pp.). Copies may be obtained through The Executive Secretary, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.

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